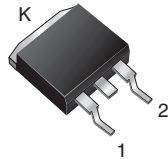
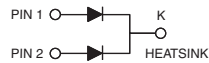


Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.28\text{ V}$ at $I_F = 5.0\text{ A}$
TMBS®
D²PAK (TO-263AB)

VBT4045C

DESIGN SUPPORT TOOLS
[click logo to get started](#)
3D
 Models
 Available

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 20 A
V_{RRM}	45 V
I_{FSM}	240 A
V_F at $I_F = 20\text{ A}$	0.41 V
T_J max.	150 °C
Package	D ² PAK (TO-263AB)
Circuit configuration	Common cathode

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA
Case: D²PAK (TO-263AB)

 Molding compound meets UL 94 V-0 flammability rating
 Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VBT4045C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	40
		per diode	20
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	240	A
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.41	-	V
	$I_F = 10\text{ A}$			0.44	-	
	$I_F = 20\text{ A}$			0.50	0.58	
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.28	-	
	$I_F = 10\text{ A}$			0.33	-	
	$I_F = 20\text{ A}$			0.41	0.50	
Reverse current per diode	$V_R = 45\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	-	3000	μA
		$T_A = 125\text{ }^\circ\text{C}$		18	50	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	VBT4045C	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	1.5	$^\circ\text{C/W}$
	per device		0.8	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VBT4045C-E3/4W	1.38	4W	50/tube	Tube
TO-263AB	VBT4045C-E3/8W	1.38	8W	800/reel	Tape and reel

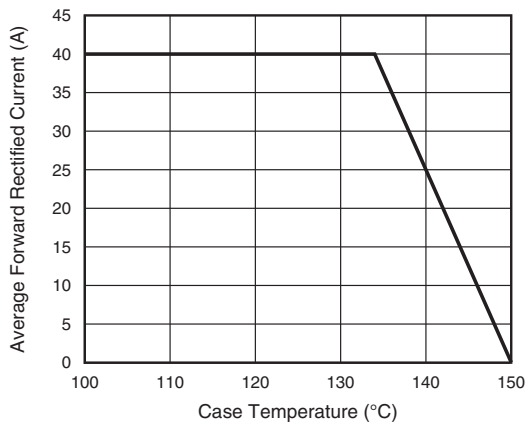
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

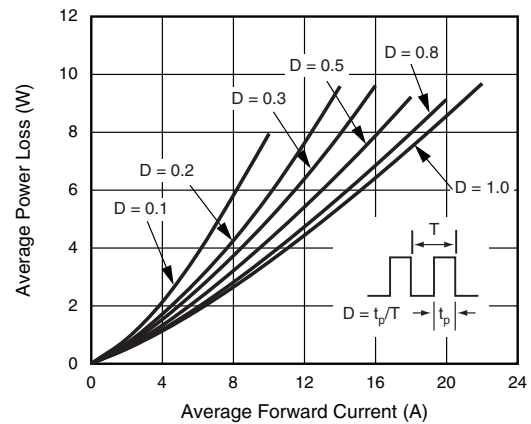


Fig. 2 - Forward Power Loss Characteristics Per Diode

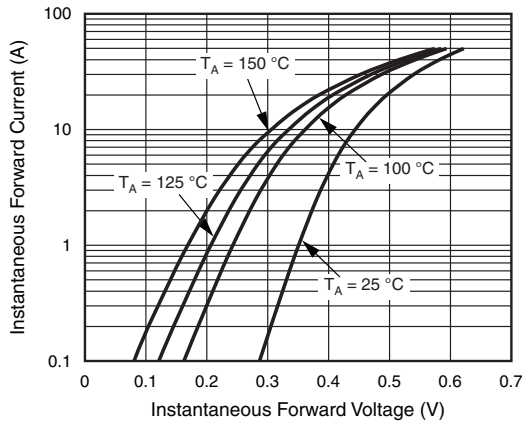


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

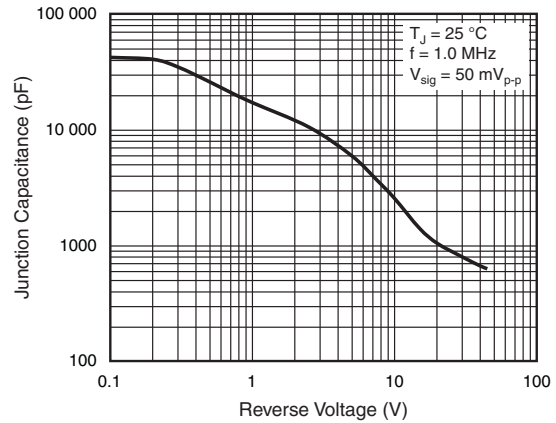


Fig. 5 - Typical Junction Capacitance Per Diode

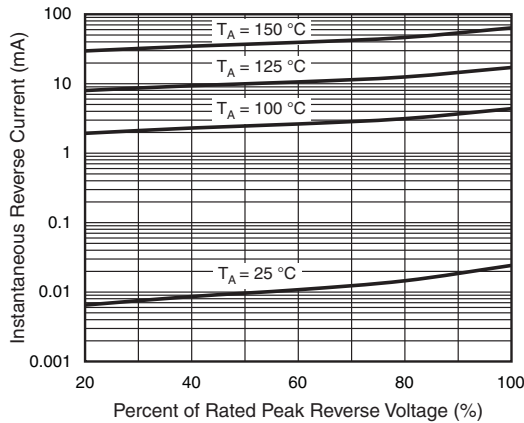


Fig. 4 - Typical Reverse Characteristics Per Diode

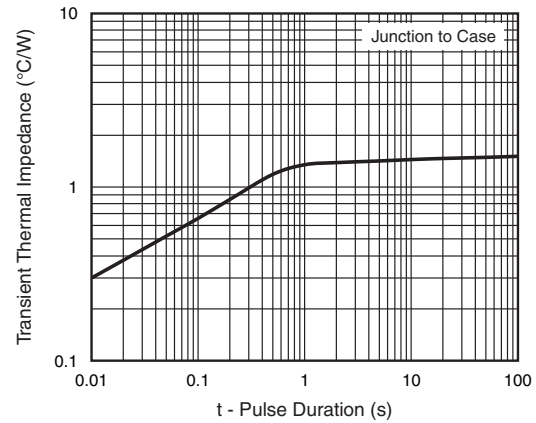
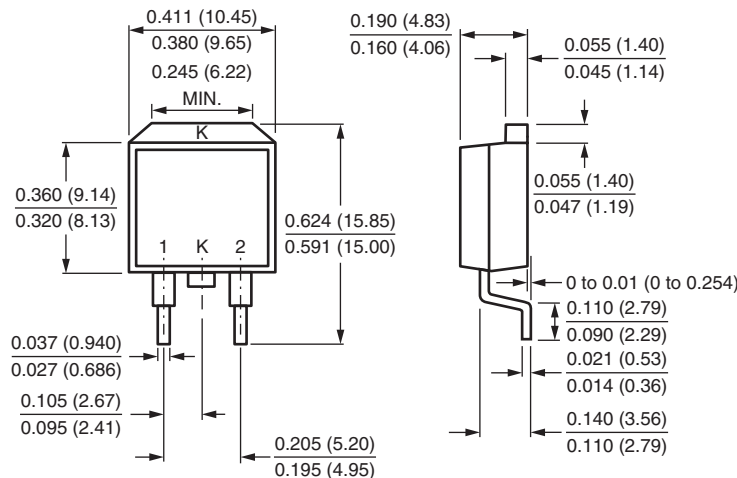


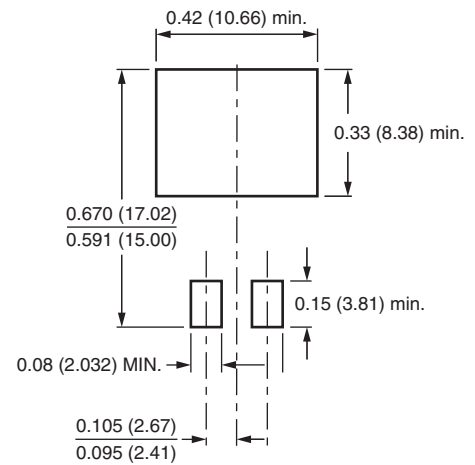
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

D²PAK (TO-263AB)



Mounting Pad Layout





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